

0902 1480 nm Pump





1425 nm Pump Laser Diode, 320 mW, PM Fiber

The pump has been designed for use in a wide variety of optical amplifiers, such as EDFA and Raman amplifiers used in optical transmission systems, especially in dense wavelength division multiplexing (DWDM) systems. A strained multi-quantum well (st-MQW) laser diode chip is integrated with thermo-electric cooler (TEC) and PIN photodiode in a hermetically sealed 14-pin butterfly package.

FEATURES

- Rated Output Powe Up to 320 mW(CW)
- Polarization Maintaining Fiber Pigtail
- 14-pin Butterfly Footprint
- Integrated PIN Photodiode for Back Facet Monitor
- Single Mode Fiber

USE IN

- Pump Source for Er-Doped Fiber Amplifier
- C- and/or L-band EDFA
- Single Channel Amp. to DWDM Amp.
- Pump Source for Raman Amplifier

Storage Temperature	-40°C to 85°C
Operation Temperature	-20°C to 70°C
LD Forward Current	1600 mA max.
LD Reverse Voltage	2 V max.
PD Forward Current	5 mA max.
PD Reverse Voltage	20 V max.
TEC Current	-1.1 A min.; 4.5 A max.
TEC Voltage	4.5 V max.
Output Power	320 mW
Forward Current	1300 mA max.
Center Wavelength	1420 nm to 1510 nm (±1.5 nm)
Forward Voltage	2.6 V max.
Forward Current at EOL	1.2xlfBOL mA max.
Monitor Current	100 μA min.; 2000 μA max.
Monitor Dark Current	100 nA max.
Extinction Ratio	16 dB min.
Thermistor Resistance	9.5 kΩ min.; 10 kΩ typ.; 10.5 kΩ max.
Thermistor B Constant	3900 typ.